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## Details

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Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	20MHz
Connectivity	-
Peripherals	Brown-out Detect/Reset, POR, WDT
Number of I/O	13
Program Memory Size	3.5KB (2K x 14)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	128 x 8
Voltage - Supply (Vcc/Vdd)	4V ~ 5.5V
Data Converters	A/D 4x8b
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	18-SOIC (0.295", 7.50mm Width)
Supplier Device Package	18-SOIC
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c715t-20i-so

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

NOTES:

## 3.0 ARCHITECTURAL OVERVIEW

The high performance of the PIC16CXX family can be attributed to a number of architectural features commonly found in RISC microprocessors. To begin with, the PIC16CXX uses a Harvard architecture, in which, program and data are accessed from separate memories using separate buses. This improves bandwidth over traditional von Neumann architecture in which program and data are fetched from the same memory using the same bus. Separating program and data buses further allows instructions to be sized differently than the 8-bit wide data word. Instruction opcodes are 14-bits wide making it possible to have all single word instructions. A 14-bit wide program memory access bus fetches a 14-bit instruction in a single cycle. A twostage pipeline overlaps fetch and execution of instructions (Example 3-1). Consequently, all instructions (35) execute in a single cycle (200 ns @ 20 MHz) except for program branches.

The table below lists program memory (EPROM) and data memory (RAM) for each PIC16C71X device.

Device	Program Memory	Data Memory
PIC16C710	512 x 14	36 x 8
PIC16C71	1K x 14	36 x 8
PIC16C711	1K x 14	68 x 8
PIC16C715	2K x 14	128 x 8

The PIC16CXX can directly or indirectly address its register files or data memory. All special function registers, including the program counter, are mapped in the data memory. The PIC16CXX has an orthogonal (symmetrical) instruction set that makes it possible to carry out any operation on any register using any addressing mode. This symmetrical nature and lack of 'special optimal situations' make programming with the PIC16CXX simple yet efficient. In addition, the learning curve is reduced significantly.

PIC16CXX devices contain an 8-bit ALU and working register. The ALU is a general purpose arithmetic unit. It performs arithmetic and Boolean functions between the data in the working register and any register file.

The ALU is 8-bits wide and capable of addition, subtraction, shift and logical operations. Unless otherwise mentioned, arithmetic operations are two's complement in nature. In two-operand instructions, typically one operand is the working register (W register). The other operand is a file register or an immediate constant. In single operand instructions, the operand is either the W register or a file register.

The W register is an 8-bit working register used for ALU operations. It is not an addressable register.

Depending on the instruction executed, the ALU may affect the values of the Carry (C), Digit Carry (DC), and Zero (Z) bits in the STATUS register. The C and DC bits operate as a borrow bit and a digit borrow out bit, respectively, in subtraction. See the SUBLW and SUBWF instructions for examples.

PIC16C71X

Example 4-1 shows the calling of a subroutine in page 1 of the program memory. This example assumes that PCLATH is saved and restored by the interrupt service routine (if interrupts are used).

## EXAMPLE 4-1: CALL OF A SUBROUTINE IN PAGE 1 FROM PAGE 0

ORG 0x5	500	
BSF	pclath,3	;Select page 1 (800h-FFFh)
BCF	pclath,4	;Only on >4K devices
CALL	SUB1_P1	;Call subroutine in
	:	;page 1 (800h-FFFh)
	:	
	:	
ORG 0x9	900	
SUB1_P1	:	;called subroutine
	:	;page 1 (800h-FFFh)
	:	
RETURN		;return to Call subroutine
		;in page 0 (000h-7FFh)

## 4.5 <u>Indirect Addressing, INDF and FSR</u> <u>Registers</u>

The INDF register is not a physical register. Addressing the INDF register will cause indirect addressing.

Indirect addressing is possible by using the INDF register. Any instruction using the INDF register actually accesses the register pointed to by the File Select Register, FSR. Reading the INDF register itself indirectly (FSR = '0') will read 00h. Writing to the INDF register indirectly results in a no-operation (although status bits may be affected). An effective 9-bit address is obtained by concatenating the 8-bit FSR register and the IRP bit (STATUS<7>), as shown in Figure 4-15. However, IRP is not used in the PIC16C71X devices.

A simple program to clear RAM locations 20h-2Fh using indirect addressing is shown in Example 4-2.

## EXAMPLE 4-2: INDIRECT ADDRESSING

	movlw	0x20	;initialize pointer
	movwf	FSR	;to RAM
NEXT	clrf	INDF	;clear INDF register
	incf	FSR,F	;inc pointer
	btfss	FSR,4	;all done?
	goto	NEXT	;no clear next
CONTINUE			
	:		;yes continue

## FIGURE 4-15: DIRECT/INDIRECT ADDRESSING



## 5.3 I/O Programming Considerations

## 5.3.1 BI-DIRECTIONAL I/O PORTS

Any instruction which writes, operates internally as a read followed by a write operation. The BCF and BSF instructions, for example, read the register into the CPU, execute the bit operation and write the result back to the register. Caution must be used when these instructions are applied to a port with both inputs and outputs defined. For example, a BSF operation on bit5 of PORTB will cause all eight bits of PORTB to be read into the CPU. Then the BSF operation takes place on bit5 and PORTB is written to the output latches. If another bit of PORTB is used as a bi-directional I/O pin (e.g., bit0) and it is defined as an input at this time, the input signal present on the pin itself would be read into the CPU and rewritten to the data latch of this particular pin, overwriting the previous content. As long as the pin stays in the input mode, no problem occurs. However, if bit0 is switched to an output, the content of the data latch may now be unknown.

Reading the port register, reads the values of the port pins. Writing to the port register writes the value to the port latch. When using read-modify-write instructions (ex. BCF, BSF, etc.) on a port, the value of the port pins is read, the desired operation is done to this value, and this value is then written to the port latch.

Example 5-3 shows the effect of two sequential readmodify-write instructions on an I/O port.

## EXAMPLE 5-3: READ-MODIFY-WRITE INSTRUCTIONS ON AN I/O PORT

;Initial PORT settings: PORTB<7:4> Inputs
; PORTB<3:0> Outputs
;PORTB<7:6> have external pull-ups and are
;not connected to other circuitry
;

;					PORT	latch	PORT 1	pins
;								
	BCF	PORTB,	7	;	01pp	pppp	11pp	pppp
	BCF	PORTB,	б	;	10pp	pppp	11pp	pppp
	BSF	STATUS,	RP0	;				
	BCF	TRISB,	7	;	10pp	pppp	11pp	pppp
	BCF	TRISB,	б	;	10pp	pppp	10pp	pppp

;Note that the user may have expected the ;pin values to be 00pp ppp. The 2nd BCF ;caused RB7 to be latched as the pin value ;(high).

A pin actively outputting a Low or High should not be driven from external devices at the same time in order to change the level on this pin ("wired-or", "wired-and"). The resulting high output currents may damage the chip.

## 5.3.2 SUCCESSIVE OPERATIONS ON I/O PORTS

The actual write to an I/O port happens at the end of an instruction cycle, whereas for reading, the data must be valid at the beginning of the instruction cycle (Figure 5-6). Therefore, care must be exercised if a write followed by a read operation is carried out on the same I/O port. The sequence of instructions should be such to allow the pin voltage to stabilize (load dependent) before the next instruction which causes that file to be read into the CPU is executed. Otherwise, the previous state of that pin may be read into the CPU rather than the new state. When in doubt, it is better to separate these instructions with a NOP or another instruction not accessing this I/O port.

## FIGURE 5-6: SUCCESSIVE I/O OPERATION



## 6.0 TIMER0 MODULE

## Applicable Devices71071711715

The Timer0 module timer/counter has the following features:

- 8-bit timer/counter
- Readable and writable
- 8-bit software programmable prescaler
- Internal or external clock select
- · Interrupt on overflow from FFh to 00h
- Edge select for external clock

Figure 6-1 is a simplified block diagram of the Timer0 module.

Timer mode is selected by clearing bit TOCS (OPTION<5>). In timer mode, the Timer0 module will increment every instruction cycle (without prescaler). If the TMR0 register is written, the increment is inhibited for the following two instruction cycles (Figure 6-2 and Figure 6-3). The user can work around this by writing an adjusted value to the TMR0 register.

Counter mode is selected by setting bit TOCS (OPTION<5>). In counter mode, Timer0 will increment either on every rising or falling edge of pin RA4/T0CKI. The incrementing edge is determined by the Timer0 Source Edge Select bit TOSE (OPTION<4>). Clearing

FIGURE 6-1: TIMER0 BLOCK DIAGRAM

bit T0SE selects the rising edge. Restrictions on the external clock input are discussed in detail in Section 6.2.

The prescaler is mutually exclusively shared between the Timer0 module and the Watchdog Timer. The prescaler assignment is controlled in software by control bit PSA (OPTION<3>). Clearing bit PSA will assign the prescaler to the Timer0 module. The prescaler is not readable or writable. When the prescaler is assigned to the Timer0 module, prescale values of 1:2, 1:4, ..., 1:256 are selectable. Section 6.3 details the operation of the prescaler.

## 6.1 <u>Timer0 Interrupt</u>

The TMR0 interrupt is generated when the TMR0 register overflows from FFh to 00h. This overflow sets bit T0IF (INTCON<2>). The interrupt can be masked by clearing bit T0IE (INTCON<5>). Bit T0IF must be cleared in software by the Timer0 module interrupt service routine before re-enabling this interrupt. The TMR0 interrupt cannot awaken the processor from SLEEP since the timer is shut off during SLEEP. See Figure 6-4 for Timer0 interrupt timing.



## FIGURE 6-2: TIMER0 TIMING: INTERNAL CLOCK/NO PRESCALE



## 6.3.1 SWITCHING PRESCALER ASSIGNMENT

The prescaler assignment is fully under software control, i.e., it can be changed "on the fly" during program execution. **Note:** To avoid an unintended device RESET, the following instruction sequence (shown in Example 6-1) must be executed when changing the prescaler assignment from Timer0 to the WDT. This sequence must be followed even if the WDT is disabled.

## EXAMPLE 6-1: CHANGING PRESCALER (TIMER0→WDT)

BCFSTATUS, RP0;Bank 0CLRFTMR0;Clear TMR0 & PrescalerBSFSTATUS, RP0;Bank 1CLRWDT;Clears WDTMOVLWb'xxxxlxxx';Selects new prescale valueMOVWFOPTION\_REG;and assigns the prescaler to the WDTBCFSTATUS, RP0;Bank 0

To change prescaler from the WDT to the Timer0 module use the sequence shown in Example 6-2.

## EXAMPLE 6-2: CHANGING PRESCALER (WDT → TIMER0)

CLRWDT		;Clear WDT and prescaler
BSF	STATUS, RPO	;Bank 1
MOVLW	b'xxxx0xxx'	;Select TMR0, new prescale value and
MOVWF	OPTION_REG	;clock source
BCF	STATUS, RPO	;Bank 0

## TABLE 6-1: REGISTERS ASSOCIATED WITH TIMER0

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on: POR, BOR	Value on all other resets	
01h	TMR0	Timer0	module's r	egister						xxxx xxxx	uuuu uuuu	
0Bh,8Bh,	INTCON	GIE	ADIE	TOIE	INTE	RBIE	TOIF	INTF	RBIF	0000 000x	0000 000u	
81h	OPTION	RBPU	INTEDG	TOCS	TOSE	PSA	PS2	PS1	PS0	1111 1111	1111 1111	
85h	TRISA	_	—	—	PORTA I	Data Direc	tion Regi	1 1111	1 1111			

Legend: x = unknown, u = unchanged, - = unimplemented locations read as '0'. Shaded cells are not used by Timer0.

The ADRES register contains the result of the A/D conversion. When the A/D conversion is complete, the result is loaded into the ADRES register, the GO/DONE bit (ADCON0<2>) is cleared, and A/D interrupt flag bit ADIF is set. The block diagram of the A/D module is shown in Figure 7-4.

After the A/D module has been configured as desired, the selected channel must be acquired before the conversion is started. The analog input channels must have their corresponding TRIS bits selected as an input. To determine acquisition time, see Section 7.1. After this acquisition time has elapsed the A/D conversion can be started. The following steps should be followed for doing an A/D conversion:

- 1. Configure the A/D module:
  - Configure analog pins / voltage reference / and digital I/O (ADCON1)
  - Select A/D input channel (ADCON0)
  - Select A/D conversion clock (ADCON0)
  - Turn on A/D module (ADCON0)

- Set GIE bit
  - 3. Wait the required acquisition time.

2. Configure A/D interrupt (if desired):

4. Start conversion:

Clear ADIF bit

Set ADIE bit

- Set GO/DONE bit (ADCON0)
- 5. Wait for A/D conversion to complete, by either:Polling for the GO/DONE bit to be cleared
  - OR
  - Waiting for the A/D interrupt
- 6. Read A/D Result register (ADRES), clear bit ADIF if required.
- 7. For next conversion, go to step 1 or step 2 as required. The A/D conversion time per bit is defined as TAD. A minimum wait of 2TAD is required before next acquisition starts.



## FIGURE 7-4: A/D BLOCK DIAGRAM

## 7.1 A/D Acquisition Requirements

For the A/D converter to meet its specified accuracy, the charge holding capacitor (CHOLD) must be allowed to fully charge to the input channel voltage level. The analog input model is shown in Figure 7-5. The source impedance (Rs) and the internal sampling switch (Rss) impedance directly affect the time required to charge the capacitor CHOLD. The sampling switch (Rss) impedance varies over the device voltage (VDD), Figure 7-5. The source impedance affects the offset voltage at the analog input (due to pin leakage current). **The maximum recommended impedance for analog sources is 10 k** $\Omega$ . After the analog input channel is selected (changed) this acquisition must be done before the conversion can be started.

To calculate the minimum acquisition time, Equation 7-1 may be used. This equation calculates the acquisition time to within 1/2 LSb error is used (512 steps for the A/D). The 1/2 LSb error is the maximum error allowed for the A/D to meet its specified accuracy.

## EQUATION 7-1: A/D MINIMUM CHARGING TIME

 $\mathsf{VHOLD} = (\mathsf{VREF} - (\mathsf{VREF}/\mathsf{512})) \bullet (1 - e^{(\mathsf{-TCAP/CHOLD}(\mathsf{Ric} + \mathsf{Rss} + \mathsf{Rs}))})$ 

Given: VHOLD = (VREF/512), for 1/2 LSb resolution

The above equation reduces to:

 $TCAP = -(51.2 \text{ pF})(1 \text{ k}\Omega + \text{Rss} + \text{Rs}) \ln(1/511)$ 

Example 7-1 shows the calculation of the minimum required acquisition time TACQ. This calculation is based on the following system assumptions.

CHOLD = 51.2 pF

 $Rs = 10 \ k\Omega$ 

1/2 LSb error

 $V\text{DD} = 5\text{V} \rightarrow \text{Rss} = 7 \text{ k}\Omega$ 

Temp (application system max.) = 50°C

 $\mathsf{VHOLD}=0 @ t=0$ 



## FIGURE 7-5: ANALOG INPUT MODEL

- Note 1: The reference voltage (VREF) has no effect on the equation, since it cancels itself out.
- Note 2: The charge holding capacitor (CHOLD) is not discharged after each conversion.
- Note 3: The maximum recommended impedance for analog sources is 10 k $\Omega$ . This is required to meet the pin leakage specification.
- Note 4: After a conversion has completed, a 2.0TAD delay must complete before acquisition can begin again. During this time the holding capacitor is not connected to the selected A/D input channel.

## EXAMPLE 7-1: CALCULATING THE MINIMUM REQUIRED AQUISITION TIME

TACQ = Amplifier Settling Time +

Holding Capacitor Charging Time + Temperature Coefficient

- TACQ =  $5 \,\mu s + TCAP + [(Temp 25^{\circ}C)(0.05 \,\mu s/^{\circ}C)]$
- TCAP = -CHOLD (RIC + RSS + RS) ln(1/511)
  - -51.2 pF (1 kΩ + 7 kΩ + 10 kΩ) ln(0.0020) -51.2 pF (18 kΩ) ln(0.0020) -0.921 μs (-6.2364)

5.747 μs

TACQ = 5 μs + 5.747 μs + [(50°C - 25°C)(0.05 μs/°C)] 10.747 μs + 1.25 μs 11.997 μs

## 7.4.1 FASTER CONVERSION - LOWER RESOLUTION TRADE-OFF

Not all applications require a result with 8-bits of resolution, but may instead require a faster conversion time. The A/D module allows users to make the trade-off of conversion speed to resolution. Regardless of the resolution required, the acquisition time is the same. To speed up the conversion, the clock source of the A/D module may be switched so that the TAD time violates the minimum specified time (see the applicable electrical specification). Once the TAD time violates the minimum specified time, all the following A/D result bits are not valid (see A/D Conversion Timing in the Electrical Specifications section.) The clock sources may only be switched between the three oscillator versions (cannot be switched from/to RC). The equation to determine the time before the oscillator can be switched is as follows:

Conversion time =  $2TAD + N \cdot TAD + (8 - N)(2TOSC)$ Where: N = number of bits of resolution required. Since the TAD is based from the device oscillator, the user must use some method (a timer, software loop, etc.) to determine when the A/D oscillator may be changed. Example 7-3 shows a comparison of time required for a conversion with 4-bits of resolution, versus the 8-bit resolution conversion. The example is for devices operating at 20 MHz and 16 MHz (The A/D clock is programmed for 32TOSC), and assumes that immediately after 6TAD, the A/D clock is programmed for 2TOSC.

The 2Tosc violates the minimum TAD time since the last 4-bits will not be converted to correct values.

EXAMPLE 7-3:	4-BIT vs. 8-BIT CONVERSION TIMES

	- (1)	Resolution			
	Freq. (MHz)(")	4-bit	8-bit		
TAD	20	1.6 μs	1.6 μs		
	16	2.0 μs	2.0 μs		
Tosc	20	50 ns	50 ns		
	16	62.5 ns	62.5 ns		
2TAD + N • TAD + (8 - N)(2TOSC)	20	10 μs	16 μs		
	16	12.5 μs	20 µs		

Note 1: The PIC16C71 has a minimum TAD time of 2.0 µs.

All other PIC16C71X devices have a minimum TAD time of 1.6  $\mu$ s.

## FIGURE 8-2: CONFIGURATION WORD, PIC16C710/711

CP0	CF	0 C	P0	CP0	CP0	CP0	CP0	BODEN	CP0	CP0	PWRTE	WDTE	FOSC1	FOSC0	Register:	CONFIG
oit13														bit0	Address	2007h
bit 13- 5- bit 6:	-7 4:	<b>CP0:</b> 1 = C 0 = Al <b>BODE</b> 1 = B 0 = B	Cod ode II me E <b>N:</b> I OR ( OR (	le prote protec emory i Brown- enable disable	ection b tion off is code out Re d	protec set En	ted, bu able bi	ut 00h - 3 <sub>t</sub> (1)	Fh is w	vritable						
bit 3:		<b>PWR</b> 1 = P' 0 = P'	TE: WR1 WR1	Power- Γ disab Γ enab	up Tim led led	er Ena	ble bit	(1)								
bit 2:		<b>WDTI</b> 1 = W 0 = W	E: W /DT /DT	/atchdo enable disable	og Time d ed	er Enab	le bit									
bit 1-C	):	FOSC 11 =   10 =   01 = 2 00 =	C1:F RC o HS o XT o LP o	OSCO oscillat oscillat oscillato	: Oscilla or or or or or	ator Se	lection	bits								
Note	1:	Enabl Ensur	ling l re th	Brown∙ e Powe	out Re er-up T	set aut imer is	omatic enable	ally enated anytim	oles Po ne Brov	wer-up vn-out f	Timer (F Reset is	WRT) enabled	regardle d.	ess of the	e value of bit $\overline{F}$	PWRTE.

## 2: All of the CP0 bits have to be given the same value to enable the code protection scheme listed.

## FIGURE 8-3: CONFIGURATION WORD, PIC16C715

CP1	CP0	CP1	CP0	CP1	CP0	MPEEN	BODEN	CP1	CP0	PWRTE	WDTE	FOSC1	FOSC0	Register:	CONFIG
bit13		bit0 Address 2007h											2007h		
bit 13- 5-	bit 13-8 <b>CP1:CP0:</b> Code Protection bits <sup>(2)</sup> 5-4: 11 = Code protection off 10 = Upper half of program memory code protected 01 = Upper 3/4th of program memory code protected 00 = All memory is code protected														
bit 7:	bit 7: <b>MPEEN:</b> Memory Parity Error Enable 1 = Memory Parity Checking is enabled 0 = Memory Parity Checking is disabled														
bit 6:	<b>B</b> ( 1 0	BODEN: Brown-out Reset Enable bit <sup>(1)</sup> 1 = BOR enabled 0 = BOR disabled													
bit 3:	<b>P</b> 1 0	<b>WRTE:</b> = PWR = PWR	Powe T disa T enal	r-up Ti bled bled	mer Ei	nable bit	(1)								
bit 2:	<b>W</b> 1 0	<b>DTE:</b> V = WDT = WDT	Vatchd enabl disabl	log Tin ed led	ner En	able bit									
bit 1-(	D: F( 11 10 01 00	FOSC1:FOSC0: Oscillator Selection bits 11 = RC oscillator 10 = HS oscillator 01 = XT oscillator 00 = LP oscillator													
Note	1: Er Er 2: Al	nabling nsure th I of the	Browr he Pov CP1:0	n-out R ver-up CP0 pa	teset a Timer airs har	utomatio is enable ve to be	cally enal ed anytin given the	oles Po ne Brov e same	wer-up wn-out value	o Timer (f Reset is to enable	PWRT) enable the co	regardle d. de prote	ess of the	value of bit l eme listed.	PWRTE.

## 8.3 <u>Reset</u>

## Applicable Devices 710 71 711 715

The PIC16CXX differentiates between various kinds of reset:

- Power-on Reset (POR)
- MCLR reset during normal operation
- MCLR reset during SLEEP
- WDT Reset (normal operation)
- Brown-out Reset (BOR) (PIC16C710/711/715)
- Parity Error Reset (PIC16C715)

Some registers are not affected in any reset condition; their status is unknown on POR and unchanged in any other reset. Most other registers are reset to a "reset state" on Power-on Reset (POR), on the  $\overline{\text{MCLR}}$  and

WDT Reset, on MCLR reset during SLEEP, and Brownout Reset (BOR). They are not affected by a WDT Wake-up, which is viewed as the resumption of normal operation. The TO and PD bits are set or cleared differently in different reset situations as indicated in Table 8-7, Table 8-8 and Table 8-9. These bits are used in software to determine the nature of the reset. See Table 8-10 and Table 8-11 for a full description of reset states of all registers.

A simplified block diagram of the on-chip reset circuit is shown in Figure 8-9.

The PIC16C710/711/715 have a  $\overline{\text{MCLR}}$  noise filter in the  $\overline{\text{MCLR}}$  reset path. The filter will detect and ignore small pulses.

It should be noted that a WDT Reset does not drive  $\overline{\text{MCLR}}$  pin low.



## FIGURE 8-9: SIMPLIFIED BLOCK DIAGRAM OF ON-CHIP RESET CIRCUIT

#### 8.5.1 INT INTERRUPT

External interrupt on RB0/INT pin is edge triggered: either rising if bit INTEDG (OPTION<6>) is set, or falling, if the INTEDG bit is clear. When a valid edge appears on the RB0/INT pin, flag bit INTF (INTCON<1>) is set. This interrupt can be disabled by clearing enable bit INTE (INTCON<4>). Flag bit INTF must be cleared in software in the interrupt service routine before re-enabling this interrupt. The INT interrupt can wake-up the processor from SLEEP, if bit INTE was set prior to going into SLEEP. The status of global interrupt enable bit GIE decides whether or not the processor branches to the interrupt vector following wake-up. See Section 8.8 for details on SLEEP mode.

#### 8.5.2 TMR0 INTERRUPT

An overflow (FFh  $\rightarrow$  00h) in the TMR0 register will set flag bit T0IF (INTCON<2>). The interrupt can be enabled/disabled by setting/clearing enable bit T0IE (INTCON<5>). (Section 6.0)

#### 8.5.3 PORTB INTCON CHANGE

An input change on PORTB<7:4> sets flag bit RBIF (INTCON<0>). The interrupt can be enabled/disabled by setting/clearing enable bit RBIE (INTCON<4>). (Section 5.2)

For the PIC16C71 Note: if a change on the I/O pin should occur when the read operation is being executed (start of the Q2 cycle), then the RBIF interrupt flag may not get set.

	Q1   Q2   Q3   Q4	Q1   Q2   Q3   Q4	Q1   Q2   Q3   Q4	Q1   Q2   Q3   Q4	Q1   Q2   Q3   Q4
OSC1 /					
CLKOUT ③	(4)			/	
INT pin		1	1 1 1 1		1 1 1 1 1 1 1 1
INTF flag (INTCON<1>)			Interrupt Latency (2)		
GIE bit (INTCON<7>)					
INSTRUCTION	FLOW		, , , , , , , , , , , , , , , , , , , ,		· · · · · · · · · · · · · · · · · · ·
PC	PC	PC+1	PC+1	X 0004h	X 0005h
Instruction ( fetched	Inst (PC)	Inst (PC+1)	_	Inst (0004h)	Inst (0005h)
Instruction {	Inst (PC-1)	Inst (PC)	Dummy Cycle	Dummy Cycle	Inst (0004h)

## FIGURE 8-19: INT PIN INTERRUPT TIMING

Note 1: INTF flag is sampled here (every Q1).

2: Interrupt latency = 3-4 Tcy where Tcy = instruction cycle time. Latency is the same whether Inst (PC) is a single cycle or a 2-cycle instruction.

3: CLKOUT is available only in RC oscillator mode. 4: For minimum width of INT pulse, refer to AC specs.

5: INTF is enabled to be set anytime during the Q4-Q1 cycles.

BTFSS	Bit Test f	f, Skip if S	Set		CALL	Call Sub	routine			
Syntax:	[ <i>label</i> ] B1	FSS f,b			Syntax:	[ label ]				
Operands:	0 ≤ f ≤ 12 0 ≤ b < 7	27			Operands:	$0 \le k \le 2047$				
Operation:	skip if (f<	skip if (f <b>) = 1</b>			Operation.	$(PC)+1 \rightarrow 10S,$ $k \rightarrow PC < 10:0>,$ $(PC) ATH (4:22) \rightarrow PC (12:11)$				
Status Affected:	None				Status Affastad	None	$(FOLATH<4.3>) \to FO<12.11>$			
Encoding:	01	11bb	bfff	ffff	Status Allected:	None				
Description:	If bit 'b' in register 'f' is '0' then the next instruction is executed. If bit 'b' is '1', then the next instruction is discarded and a NOP is executed instead, making this a 2TCY instruction.			Encoding: Description:	10         0kkk         kkkk         kkkk           Call Subroutine. First, return address         (PC+1) is pushed onto the stack. The eleven bit immediate address is loaded into PC bits <10:0>. The upper bits of			kkkk ddress ck. The s loaded r bits of		
Words:	1					the PC are	e loaded fi two cycle	om PCLA	TH.	
Cycles:	1(2)				Words.	1				
Q Cycle Activity:	Q1	Q2	Q3	Q4	Cvcles:	2				
	Decode	Read register 'f'	Process data	NOP	Q Cycle Activity:	Q1	Q2	Q3	Q4	
If Skip:	(2nd Cyc	le)			1st Cycle	Decode	Read literal 'k',	Process data	Write to PC	
	Q1	Q2	Q3	Q4			Push PC to Stack			
	NOP	NOP	NOP	NOP	2nd Cycle	NOP	NOP	NOP	NOP	
Example	HERE FALSE	BTFSC GOTO	FLAG,1 PROCESS	CODE	Example	HERE	CALL	THERE		
	TRUE	•				Before In After Inst	struction PC = A ruction	ddress HE	CRE	
	Before In After Inst	struction PC = a ruction if FLAG<1> PC = a if FLAG<1>	address $H$ > = 0, address $FT$ > = 1,	IERE			PC = A TOS = A	ddress TH ddress HH	IERE CRE+1	

# PIC16C71X

IORWF Inclusive OR W with f								
[ label ]	IORWF	f,d						
0 ≤ f ≤ 127 d ∈ [0,1]								
(W) .OR.	$(f) \rightarrow (de)$	est)						
d: Z								
00	0100	dfff	ffff					
Inclusive OR the W register with regis- ter 'f'. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'.								
1								
1								
Q1	Q2	Q3	Q4					
Decode	Read register 'f'	Process data	Write to dest					
IORWF		RESULT,	0					
Before In	struction	1						
	RESULT	= 0x13	3					
After Inst	ruction	- 0791						
	RESULT	= 0x13	3					
	W Z	= 0x93 = 1	3					
	Inclusive [ label ] $0 \le f \le 12$ $d \in [0,1]$ (W) .OR. $\overline{Z}$ Inclusive C ter 'f'. If 'd' the W reginst placed base 1 1 Q1 Decode IORWF Before In After Inst	Inclusive OR Wy $[label]$ IORWF $0 \le f \le 127$ $d \in [0,1]$ $(W)$ .OR. $(f) \rightarrow (de)$ $\overline{Z}$ $00$ 0100Inclusive OR the Wter 'f'. If 'd' is 0 the rethe W register. If 'd'placed back in regist1Q1Q2DecodeReadregister'f'IORWFBefore InstructionRESULTWAfter InstructionRESULTW7	Inclusive OR W with f[ label ]IORWFf,d $0 \le f \le 127$ $d \in [0,1]$ $(W)$ .OR. $(f) \rightarrow (dest)$ $\overline{Z}$ $00$ 0100dfffInclusive OR the W register witter 'f'. If 'd' is 0 the result is platthe W register. If 'd' is 1 the result placed back in register 'f'.11Q1Q2Q3DecodeRead register 'f'IORWFRESULT ,Before Instruction RESULT = 0x13 W = 0x91After Instruction RESULT = 0x13 W = 0x93 Z = 1					

MOVLW	Move Literal to W								
Syntax:	[ label ]	MOVLW	/ k						
Operands:	$0 \le k \le 25$	55							
Operation:	k  ightarrow (W)								
Status Affected:	None								
Encoding:	11	00xx	kkkk	kkkk					
Description:	Description: The eight bit literal 'k' is loaded into V register. The don't cares will assembl as 0's.								
Words:	1								
Cycles:	1								
Q Cycle Activity:	Q1	Q2	Q3	Q4					
	Decode	Read literal 'k'	Process data	Write to W					
Example	MOVLW After Inst	0x5A							
		W =	0x5A						

MOVF	Move f									
Syntax:	[label] MOVF f,d									
Operands:	$\begin{array}{l} 0 \leq f \leq 127 \\ d \in \left[0,1\right] \end{array}$									
Operation:	$(f) \rightarrow (dest)$									
Status Affected:	Z									
Encoding:	00 1000 dfff fff	f								
Description:	The contents of register f is moved to a destination dependant upon the sta- tus of d. If $d = 0$ , destination is W reg- ister. If $d = 1$ , the destination is file register f itself. $d = 1$ is useful to test a file register since status flag Z is affected									
Words:	1									
Cycles:	1									
Q Cycle Activity:	Q1 Q2 Q3 Q4	4								
	Decode Read register data det	ə to st								
Example	Example MOVF FSR, 0									
After Instruction W = value in FSR regi Z = 1										

MOVWF Move W to f									
Syntax:	[ label ]	MOVW	F f						
Operands:	$0 \le f \le 12$	27							
Operation:	$(W) \rightarrow (f)$								
Status Affected:	None								
Encoding:	00 0000 1fff fff								
Description:	Move data from W register to register								
Words:	1								
Cycles:	1								
Q Cycle Activity:	Q1	Q2	Q3	Q4					
	Decode	Read register 'f'	Process data	Write register 'f'					
Example	MOVWF	OPTIC	ON_REG						
	Before In	struction OPTION W	= 0xFf = 0x4f	=					
	After Inst	ruction		_					
		OPTION W	= 0x4F = 0x4F	-					

## Applicable Devices 710 71 711 715

# FIGURE 13-4: RESET, WATCHDOG TIMER, OSCILLATOR START-UP TIMER, AND POWER-UP TIMER TIMING





# TABLE 13-4: RESET, WATCHDOG TIMER, OSCILLATOR START-UP TIMER, POWER-UP TIMER, AND BROWN-OUT RESET REQUIREMENTS

Parameter	Sym	Characteristic	Min	Тур†	Max	Units	Conditions
No.	$ \setminus \lor $	$\langle \frown \rangle$					
30	TmcL	MCLR Pulse Width (low)	2	—	_	μs	VDD = 5V, -40°C to +125°C
31*	Twdt	Watchdog Timer Time-out Period (No Prescaler)	7	18	33	ms	VDD = 5V, -40°C to +125°C
32	< Tost	Oscillation Start-up Timer Period	-	1024Tosc		-	Tosc = OSC1 period
33*	Tpwrt	Power up Timer Period	28	72	132	ms	VDD = 5V, -40°C to +125°C
34	Tioz	I/O Hi-impedance from MCLR Low or Watchdog Timer Reset	_	—	2.1	μs	
35	TBOR	Brown-out Reset pulse width	100	—		μs	$VDD \le BVDD (D005)$
36	TPER	Parity Error Reset	_	TBD	_	μs	

These parameters are characterized but not tested.

† Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Applicable Devices 710 71 711 715											
15.3	DC Characteristics: PIC16C71 PIC16C71 PIC16LC7 PIC16LC7	-04 (0 -20 (0 1-04 (0	Commerc Commerc Commerc	cial, cial, cial,	Indust Indust Indust	rial) rial) rial)					
	Standard Operating Conditions (unless otherwise stated)										
	OOperating temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ (commercial)										
DC CHA	RACTERISTICS	<b>•</b>		\/-	-40°	C _≤	$IA \leq +85^{\circ}C$ (industrial)				
	and Section 15.2										
Daram	Characteristic		Min	Conditions							
No.	Gharacteristic	Sym		1 1	WIAN	Units	Conditions				
	Input Low Voltage										
	I/O ports	VIL									
D030	with TTL buffer		Vss	-	0.15V	V	For entire VDD range				
D031	with Schmitt Trigger buffer		Vss	-	0.8V	V	$4.5 \leq VDD \leq 5.5V$				
D032	MCLR, OSC1 (in RC mode)		Vss	-	0.2Vdd	V					
D033	OSC1 (in XT, HS and LP)		Vss	-	0.3Vdd	V	Note1				
	Input High Voltage										
	I/O ports (Note 4)	Vін		-							
D040	with TTL buffer		2.0	-	Vdd	V	$4.5 \le VDD \le 5.5V$				
D040A			0.25VDD + 0.8V	-	Vdd		For entire VDD range				
D041	with Schmitt Trigger buffer		0.85Vdd	-	Vdd		For entire VDD range				
D042	MCLR, RB0/INT		0.85Vdd	-	Vdd	V					
D042A	OSC1 (XT, HS and LP)		0.7Vdd	-	Vdd	V	Note1				
D043	OSC1 (in RC mode)		0.9Vdd	-	Vdd	V					
D070	PORTB weak pull-up current	IPURB	50	250	†400	μΑ	VDD = 5V, VPIN = VSS				
	Input Leakage Current (Notes 2, 3)										
D060	I/O ports	lı∟	-	-	±1	μA	Vss $\leq$ VPIN $\leq$ VDD, Pin at hi- impedance				
D061	MCLR, RA4/T0CKI		-	-	±5	μΑ	$Vss \le VPIN \le VDD$				
D063	OSC1		-	-	±5	μA	Vss $\leq$ VPIN $\leq$ VDD, XT, HS and LP osc configuration				
	Output Low Voltage										
D080	I/O ports	Vol	-	-	0.6	V	IOL = 8.5mA, VDD = 4.5V, -40°C to +85°C				
D083	OSC2/CLKOUT (RC osc config)		-	-	0.6	V	IOL = 1.6mA, VDD = 4.5V, -40°C to +85°C				
	Output High Voltage										
D090	I/O ports (Note 3)	Vон	VDD - 0.7	-	-	V	IOH = -3.0mA, VDD = 4.5V, -40°С to +85°С				
D092	OSC2/CLKOUT (RC osc config)		Vdd - 0.7	-	-	V	IOH = -1.3mA, VDD = 4.5V, -40°С to +85°С				
D130*	Open-Drain High Voltage	Vod	-	-	14	V	RA4 pin				
·			· · · ·								

† Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: In RC oscillator configuration, the OSC1 pin is a Schmitt trigger input. It is not recommended that the PIC16C71 be driven with external clock in RC mode.

2: The leakage current on the MCLR pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltages.
 2: Negative current is defined as current sourced by the pin.

3: Negative current is defined as current sourced by the pin.

4: PIC16C71 Rev. "Ax" INT pin has a TTL input buffer. PIC16C71 Rev. "Bx" INT pin has a Schmitt Trigger input buffer.

# PIC16C71X

## Applicable Devices 710 71 711 715

## 15.5 Timing Diagrams and Specifications



## FIGURE 15-2: EXTERNAL CLOCK TIMING

## TABLE 15-2: EXTERNAL CLOCK TIMING REQUIREMENTS

Parameter No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions
	Fosc	External CLKIN Frequency	DC	—	4	MHz	XT osc mode
		(Note 1)	DC	—	4	MHz	HS osc mode (-04)
			DC	—	20	MHz	HS osc mode (-20)
			DC	—	200	kHz	LP osc mode
		Oscillator Frequency	DC	—	4	MHz	RC osc mode
		(Note 1)	0.1	_	4	MHz	XT osc mode
			1	_	4	MHz	HS osc mode
			1	—	20	MHz	HS osc mode
1	Tosc	External CLKIN Period	250	—	—	ns	XT osc mode
		(Note 1)	250	—	—	ns	HS osc mode (-04)
			50	—	—	ns	HS osc mode (-20)
			5	—	—	μs	LP osc mode
		Oscillator Period	250	—	—	ns	RC osc mode
		(Note 1)	250	—	10,000	ns	XT osc mode
			250	—	1,000	ns	HS osc mode (-04)
			50	—	1,000	ns	HS osc mode (-20)
			5	—	—	μs	LP osc mode
2	TCY	Instruction Cycle Time (Note 1)	1.0	Тсү	DC	μs	TCY = 4/Fosc
3	TosL,	External Clock in (OSC1) High or	50	—	—	ns	XT oscillator
	TosH	Low Time	2.5	—	—	μs	LP oscillator
			10	—	—	ns	HS oscillator
4	TosR,	External Clock in (OSC1) Rise or	25	_	—	ns	XT oscillator
	TosF	Fall Time	50	—	—	ns	LP oscillator
			15		—	ns	HS oscillator

† Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Instruction cycle period (TCY) equals four times the input oscillator time-base period. All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. All devices are tested to operate at "min." values with an external clock applied to the OSC1/CLKIN pin. When an external clock input is used, the "Max." cycle time limit is "DC" (no clock) for all devices. OSC2 is disconnected (has no loading) for the PIC16C71.

## Applicable Devices 710 71 711 715

Param No.	Sym	Characteristic		Min	Тур†	Max	Units	Conditions
A01	NR	Resolution		_		8 bits	bits	VREF = VDD = 5.12V, $VSS \le VAIN \le VREF$
A02	EABS	Absolute error PIC16 <b>C</b> 71		_	_	< ±1	LSb	$\label{eq:VREF} \begin{array}{l} VREF = VDD = 5.12V,\\ VSS \leq VAIN \leq VREF \end{array}$
			PIC16 <b>LC</b> 71	—	—	< ±2	LSb	VREF = VDD = 3.0V (Note 3)
A03	EIL	Integral linearity error	PIC16 <b>C</b> 71	_	_	< ±1	LSb	VREF = VDD = 5.12V, $VSS \le VAIN \le VREF$
			PIC16 <b>LC</b> 71	—	—	< ±2	LSb	VREF = VDD = 3.0V (Note 3)
A04	Edl	Differential linearity error	PIC16 <b>C</b> 71	_	_	< ±1	LSb	$\begin{array}{l} VREF=VDD=5.12V,\\ VSS\leqVAIN\leqVREF \end{array}$
			PIC16 <b>LC</b> 71	—	—	< ±2	LSb	VREF = VDD = 3.0V (Note 3)
A05	EFS	Full scale error	PIC16 <b>C</b> 71	_	_	< ±1	LSb	VREF = VDD = 5.12V, $VSS \le VAIN \le VREF$
			PIC16 <b>LC</b> 71	—	—	< ±2	LSb	VREF = VDD = 3.0V (Note 3)
A06	EOFF	Offset error	PIC16 <b>C</b> 71	_	_	< ±1	LSb	VREF = VDD = 5.12V, $VSS \le VAIN \le VREF$
			PIC16 <b>LC</b> 71	—	_	< ±2	LSb	VREF = VDD = 3.0V (Note 3)
A10	—	Monotonicity		—	guaranteed		—	$VSS \leq VAIN \leq VREF$
A20	Vref	Reference voltage		3.0V	—	Vdd + 0.3	V	
A25	VAIN	Analog input voltage		Vss - 0.3	—	Vref	V	
A30	ZAIN	Recommended impedance of analog voltage source		—	—	10.0	kΩ	
A40	IAD	A/D conversion current (VDD)		_	180		μA	Average current consump- tion when A/D is on. (Note 1)
A50	IREF	VREF input current (Note 2)	PIC16 <b>C</b> 71	10	_	1000	μΑ	During VAIN acquisition. Based on differential of VHOLD to VAIN. To charge CHOLD see Section 7.1. During A/D Conversion cycle
			PIC16 <b>LC</b> 71	_	_	1	mA μA	During VAIN acquisition. Based on differential of VHOLD to VAIN. To charge CHOLD see Section 7.1. During A/D Conversion cycle

## TABLE 15-6: A/D CONVERTER CHARACTERISTICS

These parameters are characterized but not tested.

† Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: When A/D is off, it will not consume any current other than minor leakage current. The power-down current spec includes any such leakage from the A/D module.

2: VREF current is from RA3 pin or VDD pin, whichever is selected as reference input.

3: These specifications apply if VREF = 3.0V and if VDD  $\ge$  3.0V. VAIN must be between VSS and VREF.

\*



FIGURE 16-9: VTH (INPUT THRESHOLD VOLTAGE) OF I/O PINS VS. VDD





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